

# **Study of Effect on Resonance Frequency of Piezoelectric Unimorph Cantilever for Energy Harvesting**

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# Overview

- Introduction
- Piezoelectric Effect
- Piezoelectric Cantilever
- Theoretical analysis using Matlab Simulink
- Modeling using COMSOL
- Conclusion
- References

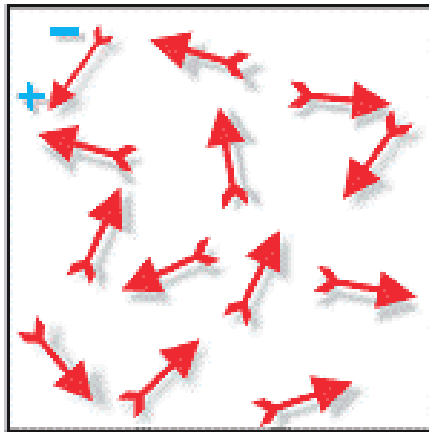
# Introduction

- At an average existing mobile Li Batteries has shelf life of 3-4 days.
- To investigate renewable power “scavenging” technologies.
- Piezoelectric materials can provide a direct transduction mechanism to convert signals from mechanical to electrical domains and vice versa.
- Piezoelectric materials are high energy density materials that are suitable for miniaturization. Therefore, this has led to a growing interest in piezoelectric thin films for MEMS applications.

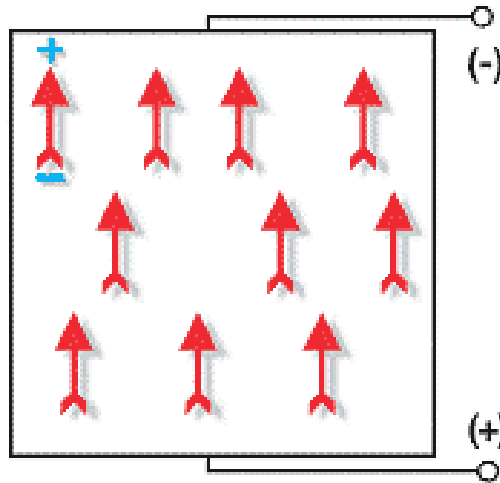
# Piezoelectric Effect

- Appearance of an electric potential across certain faces of a crystal when it is subjected to mechanical pressure
- The word originates from the greek word “piezein”, which means “to press”
- Discovered in 1880 by Pierre Curie in quartz crystals.
- Conversely, when an electric field is applied to one of the faces of the crystal it undergoes mechanical distortion.
- Examples --- Quartz, Barium titanate, tourmaline

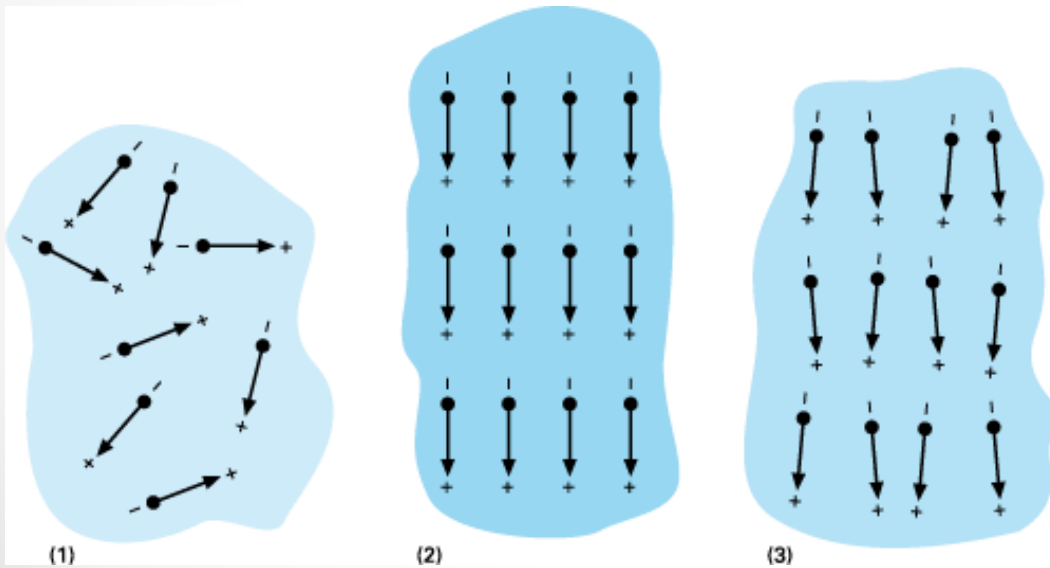
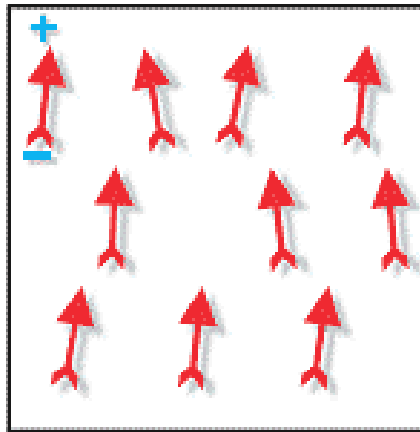
(a) random orientation of polar domains prior to polarization



(b) polarization in DC electric field

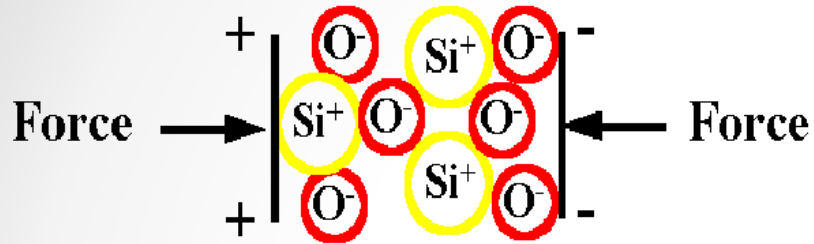


(c) remanent polarization after electric field removed

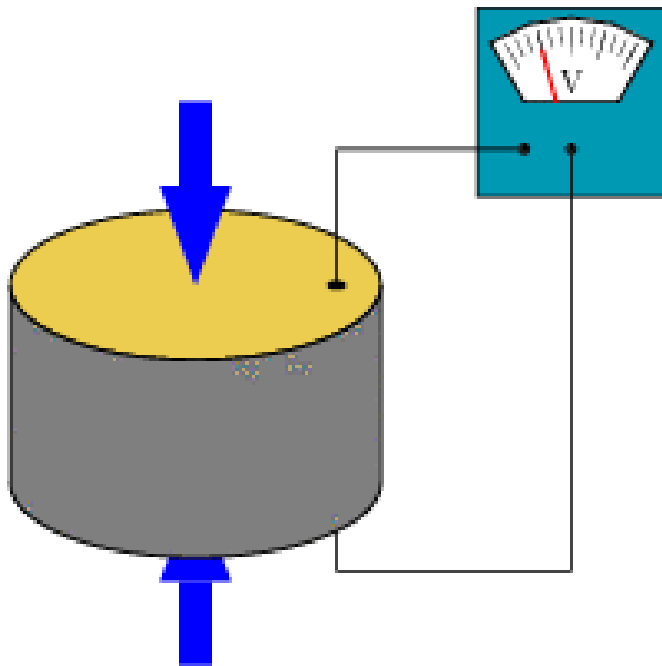


Electric dipoles in Weiss domains; (1) unpoled ferroelectric ceramic, (2) during and (3) after poling (piezoelectric ceramic)

# Piezoelectric Effect



- displacement of electrical charge due to the deflection of the lattice in a naturally piezoelectric quartz crystal
- The larger circles represent silicon atoms, while the smaller ones represent oxygen.

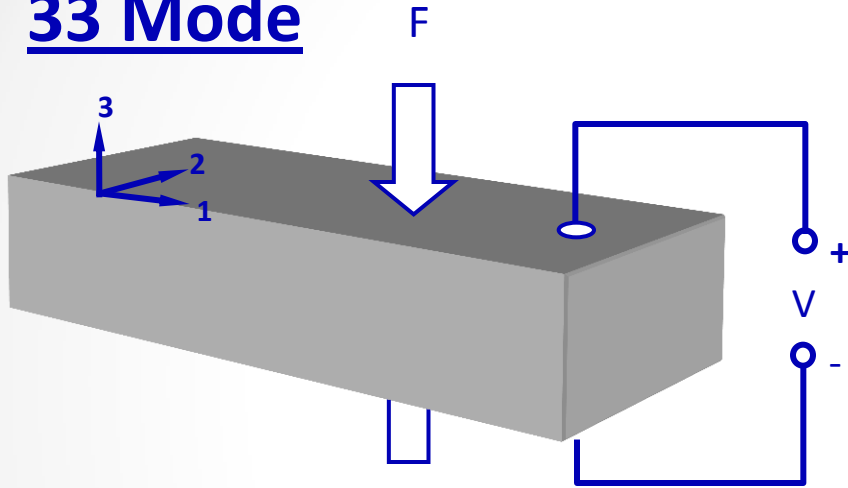


# Why Piezoelectric in MEMS

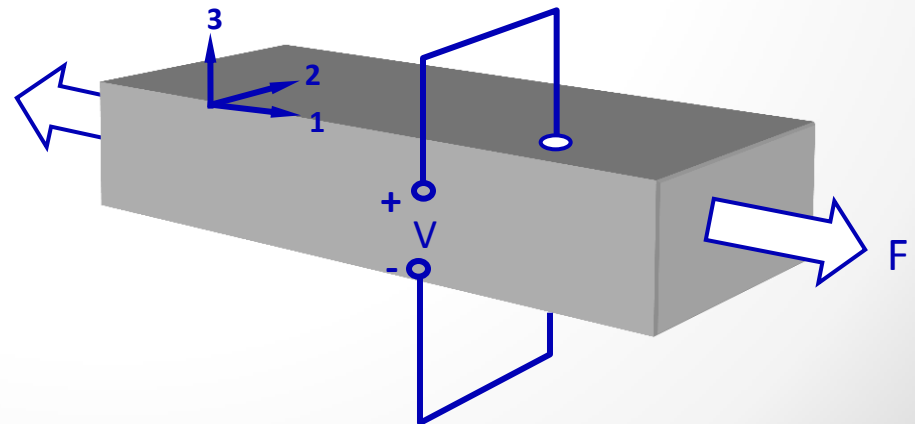
- Suitable for vibrational energy Harvesting
- Compatible with Microfabrication
- Voltages of 2-10V are obtained
- High energy density
- No separate external energy source needed
- Low maintenance
- Good efficiency

# Piezoelectric Conversion

## 33 Mode



## 31 Mode

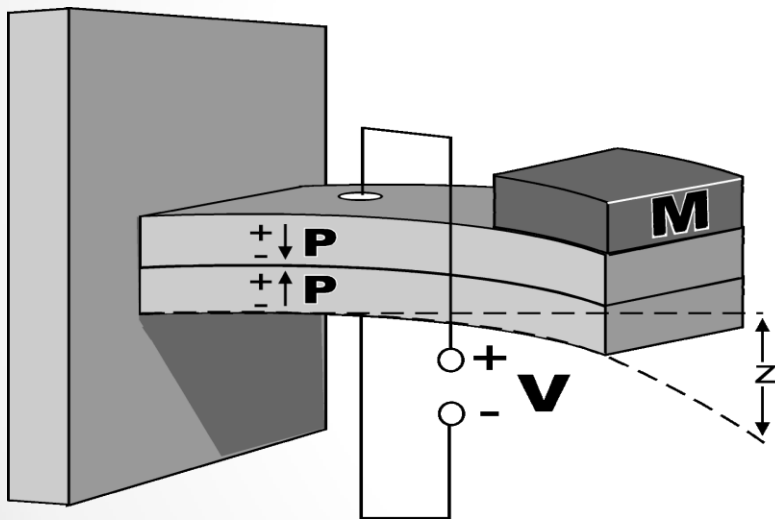




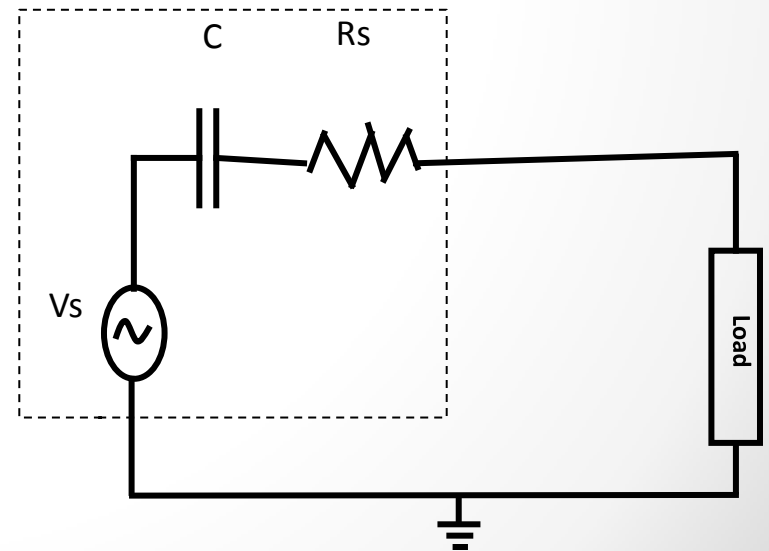
# Piezoelectric Cantilever

## Piezoelectric

Strain in piezoelectric material causes a charge separation



Piezoelectric generator

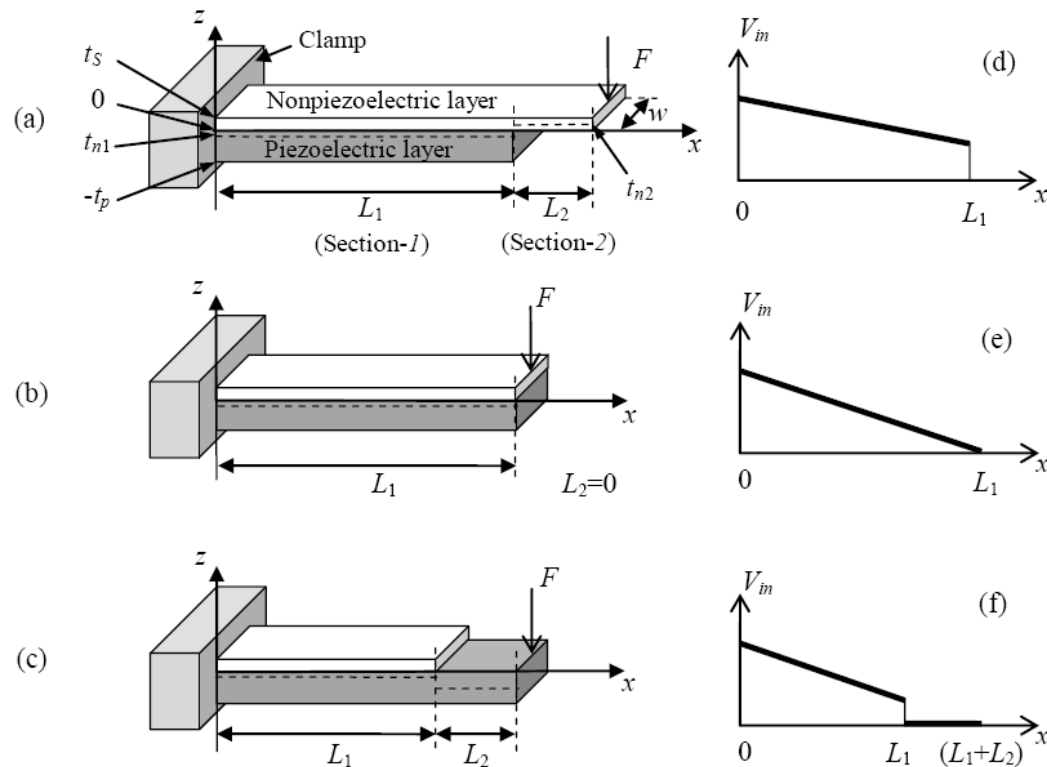


# Design and Modeling Considerations

- Good quality material
- Low resistance
- Thermal management
- Higher power and frequency of operation

# Theoretical Analysis

# Piezoelectric Unimorph Cantilevers



**Figure :** The schematic of a PUC with the NPL/PL length ratio (a)  $> 1$ , (b)  $= 1$  and (c)  $< 1$ , and the corresponding induced voltage distribution ((d), (e) and (f)) in the piezoelectric layer with a concentrated force,  $F$ , applied at the tip. Note that in (a)-(c), the dashed lines in Section-1 and Section-2 indicate the positions of the strain neutral plane.

# Piezoelectric materials are characterized by several coefficients:

<p><b><math>K_3^S</math></b> — All strains in the material are constant or mechanical deformation is blocked in any</p> <p>Electrodes are perpendicular to 3 axes. Relative dielectric constant</p>	<p><b><math>K_1^T</math></b> — All stresses on material are constant or no external forces.</p> <p>Electrodes are perpendicular to 1 axis. Relative dielectric constant.</p>
<p><b><math>k_P</math></b> — Stress or strain is equal in all directions perpendicular to 3 axis</p> <p>Electromechanical coupling factor</p>	<p><b><math>k_{15}</math></b> — Stress or strain is in shear form around 2 axis.</p> <p>Electrodes are perpendicular to 1 axis. Electromechanical coupling factor.</p>
<p><b><math>d_h</math></b> — Hydrostatic stress or stress is applied equally in all directions. Electrodes are perpendicular to 3 axis</p> <p>Piezoelectric charge coefficient.</p>	<p><b><math>d_{33}</math></b> — Applied stress, or piezoelectrically induces strain is in 3 direction.</p> <p>Electrodes are perpendicular to 3 axis. Piezoelectric charge coefficient.</p>
<p><b><math>g_{15}</math></b> — Applied stress, or the piezoelectrically induced strain in shear form around 2 axis.</p> <p>Electrodes are perpendicular to 1 axis. Piezoelectric voltage coefficient.</p>	<p><b><math>g_{31}</math></b> — Applied stress, or the piezoelectrically induced strain is in the 1 direction.</p> <p>Electrodes are perpendicular to 3 axis. Piezoelectric voltage coefficient.</p>
<p><b><math>S_{36}^E</math></b> — Compliance is measured with closed circuit.</p> <p>Stress or strain is shear around 3 direction. Strain or stress is in 3 direction Elastic compliance.</p>	<p><b><math>S_{11}^D</math></b> — Compliance is measured with open circuit.</p> <p>Stress or strain is in 1 direction. Strain or stress is in 1 direction Elastic compliance.</p>

Resonant frequency ( $f_r$ )

$$f_r = \frac{\omega}{2\pi} = \frac{1}{2\pi} \sqrt{\frac{K}{m_e}} \quad (10)$$

Expressed in terms of Bending modulus per unit width  $D_p$

$$f_n = \frac{v_n^2}{2\pi} \frac{1}{l^2} \sqrt{\frac{D_p}{m}} \quad (11)$$

$$m = \rho_p t_p + \rho_s t_s \quad (12)$$

$$D = \frac{E_p^2 t_p^4 + E_s^2 t_s^4 + 2E_p E_s t_p t_s (2t_p^2 + 2t_s^2 + 3t_p t_s)}{12(E_p t_p + E_s t_s)} \quad (13)$$

The induced voltage unit force  $V_{in,ave/F}$  is given by

$$\frac{V_{in,ave}}{F} = \frac{1}{2} L g_{31} \frac{E_p}{wD_1} \left( t_{n1} t_p + \frac{1}{2} t_p^2 \right) \quad (14)$$

$$K = \frac{2wD}{L^3} \quad (15)$$

The induced voltage per tip displacement  $V_{in,ave/htip}$  is given by

$$\frac{V_{in,ave}}{h_{tip}} = \frac{3}{4} \frac{g_{31} E_s t_s E_p t_p (t_s + t_p)}{L^2 (E_s t_s + E_p t_p)} \quad (16)$$

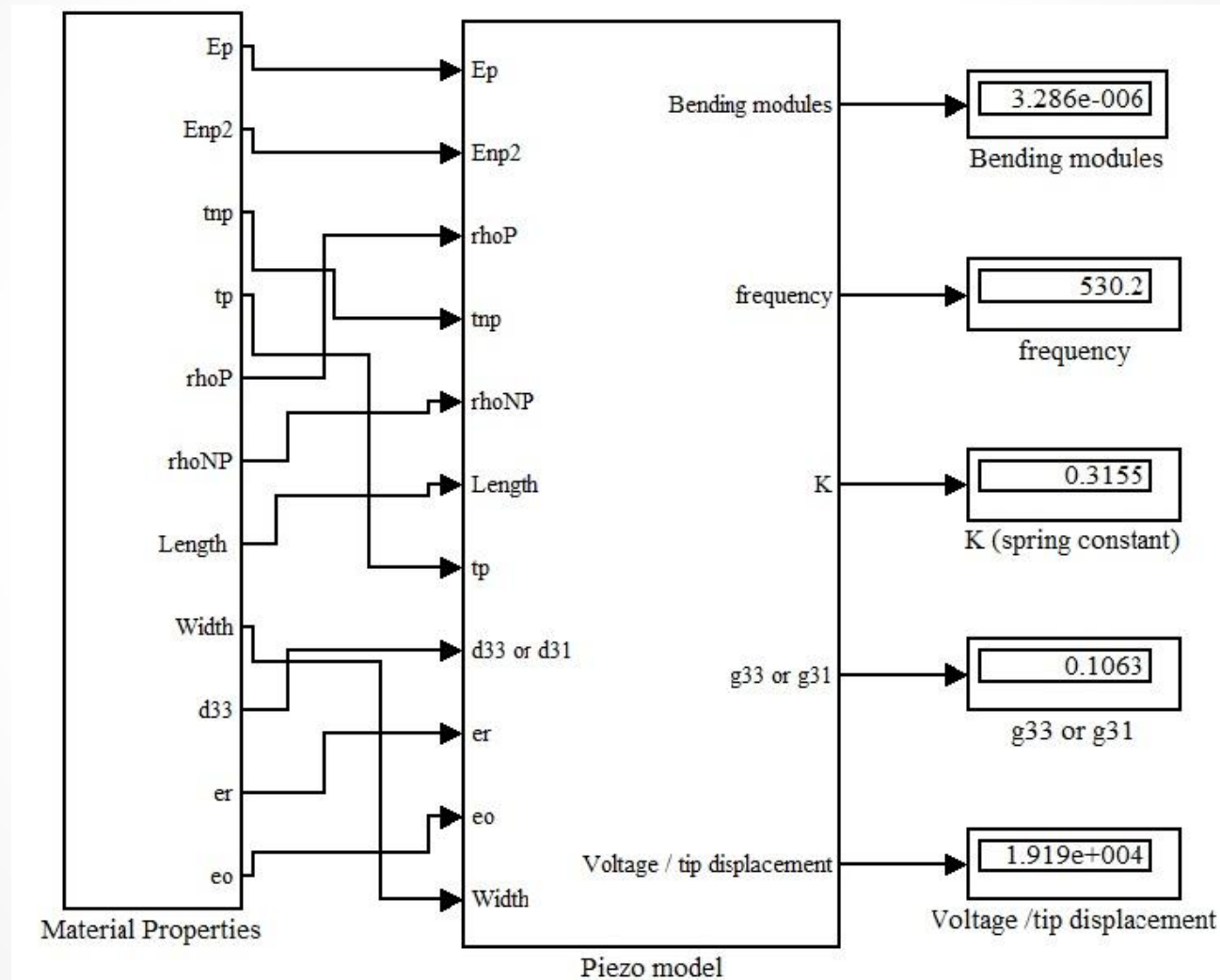
# Material properties of piezoelectric unimorph cantilever

Table :Material properties of piezoelectric unimorph cantilever

Inputs to the model	ZnO	Pt
Length( $\mu\text{m}$ )	2500	2500
Width( $\mu\text{m}$ )	500	500
thickness( $\mu\text{m}$ )	2	4
Young's modulus[GPa]	123-210	168
Poisson's ratio	--	0.38
Strain Coefficient( $10^{-12}\text{m/v}$ )	-5.4 - 11.67	--
Density( $\text{Kg/m}^3$ )	3980	21450
Dielctric Constant( $\epsilon_r$ )	9-12.64	--



# Simulink Model



**Figure. Simulink model of piezoelectric unimorph cantilever**

# Simulation using COMSOL Multiphysics

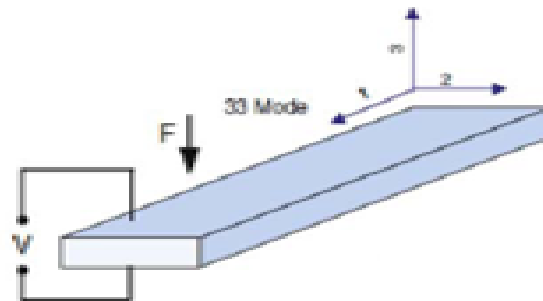
# Use of COMSOL Multiphysics

- **Application modes:**

**piezoelectric:** Mechanical / Electrical behavior

- Generated charge / Electrical potential
- Vertical vibrations application

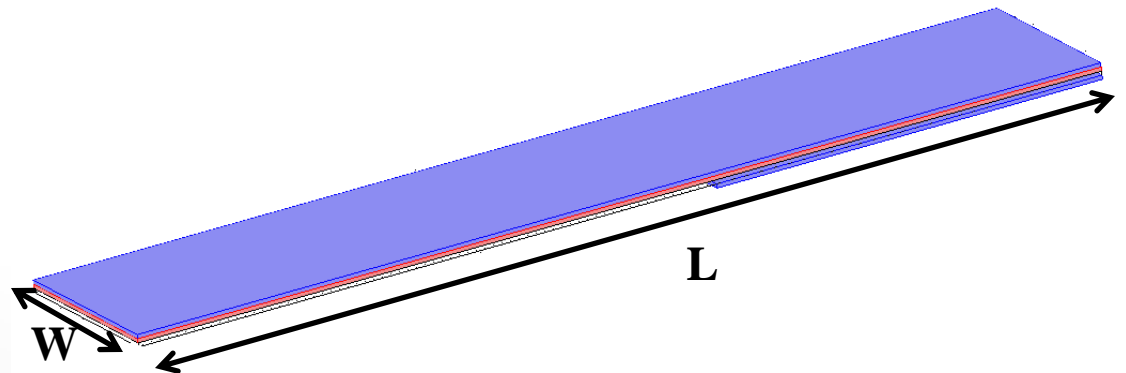
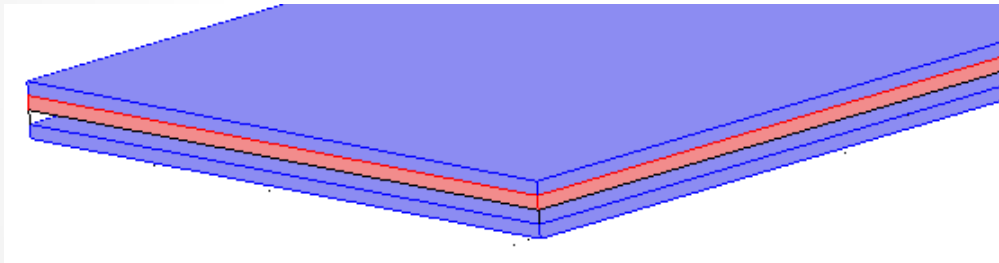
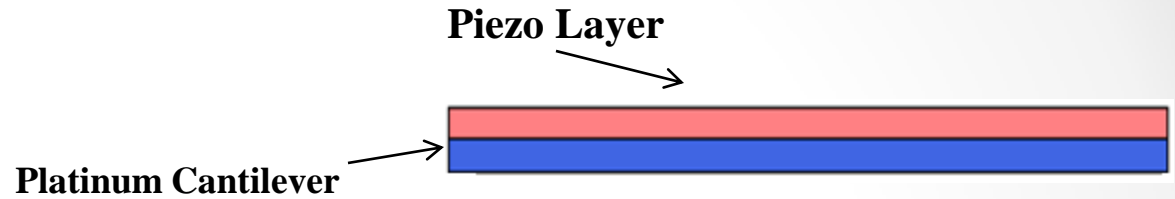
**Moving Mesh:** Varying Length



# Geometry

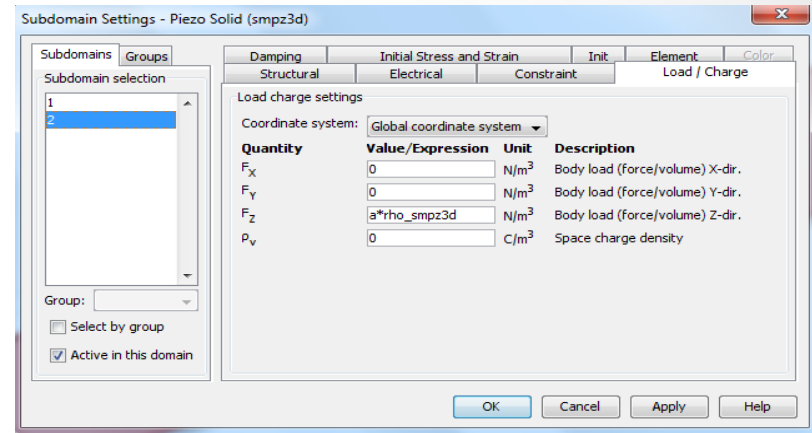
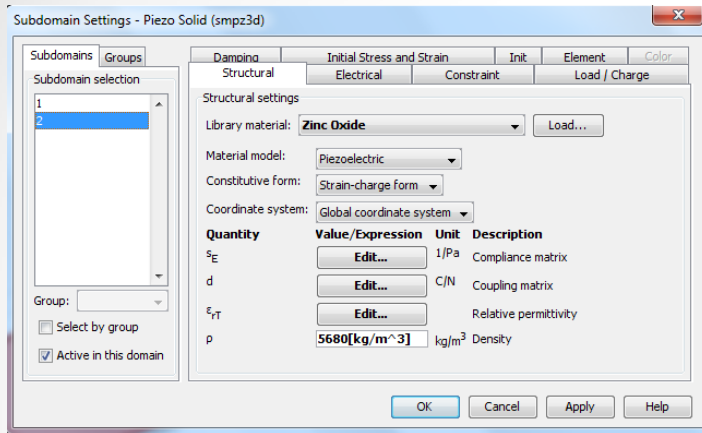
- **3D cantilever**

- length  $L = 2500\mu\text{m}$ ;
- width  $w = 500\mu\text{m}$ ;
- piezoelectric layer thickness  $t_{\text{ZnO}} = 2\mu\text{m}$ .
- Substrate layer  $t_{\text{sub}} = 4\mu\text{m}$ .



# Subdomain and Boundary settings

- Subdomain

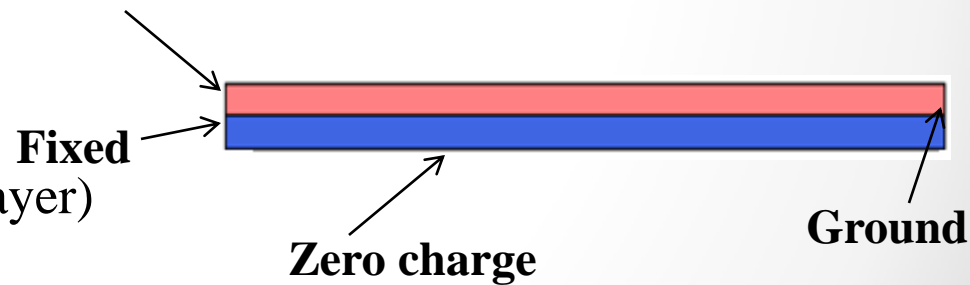


- Mechanical boundary conditions **Floating potential**

- fixed end

- Electric boundary conditions (piezo layer)

- Free end: grounded
- fixed end: floating potential
- other surfaces: zero charge



# Governing equations

- Piezoelectric Equations in strain-charge form

$$S = s^E T + dE$$

$$D = \varepsilon^T E + dT$$

$S$  = mechanical strain

$T$  = mechanical stress [ $N/m^2$ ]

$s^E$  = elastic compliance [ $Pa^{-1}$ ]

$d$  = piezoelectric coefficient [ $C/N$ ]

$D$  = electric displacement [ $C/m^2$ ]

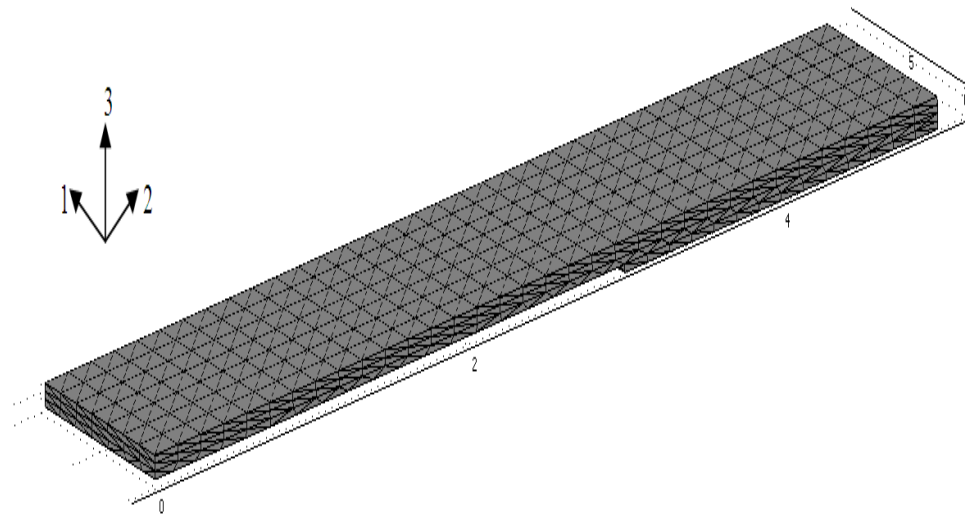
$E$  = electric field [ $V/m$ ]

$\varepsilon^T$  = dielectric permittivity [ $F/m$ ]

$$\rho = 5680 \text{ Kg} / \text{m}^3$$

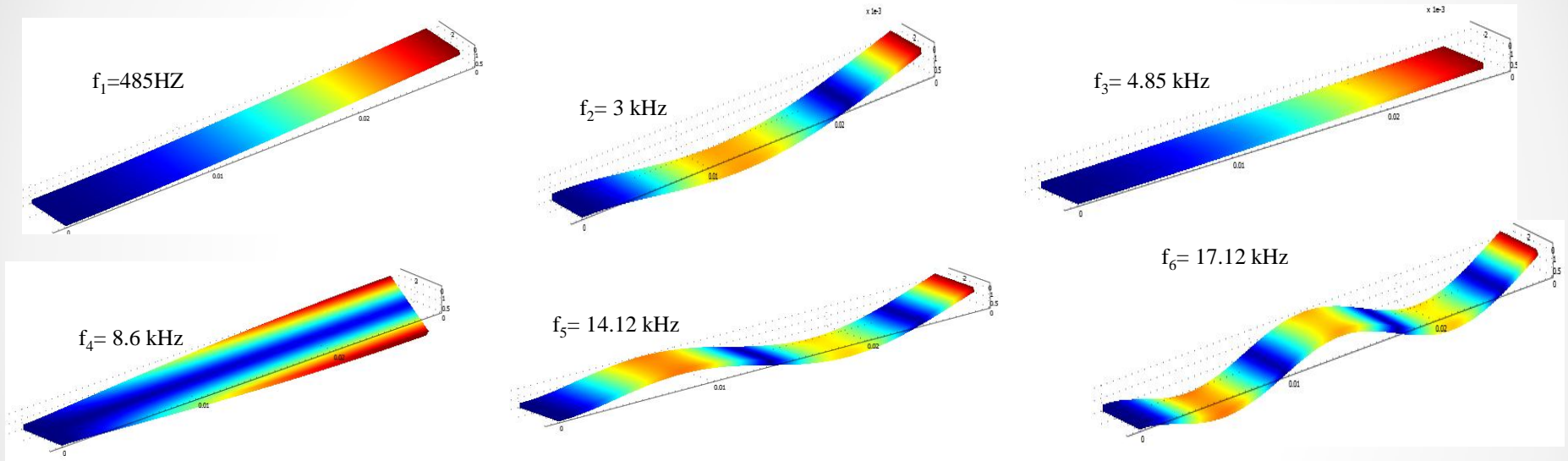
# Meshing

- **Mapped mesh Parameter**



# Simulation Results

## Eigen Frequency Analysis



**Figure .Model frequency of piezoelectric unimorph cantilever.**



# Stationary Analysis

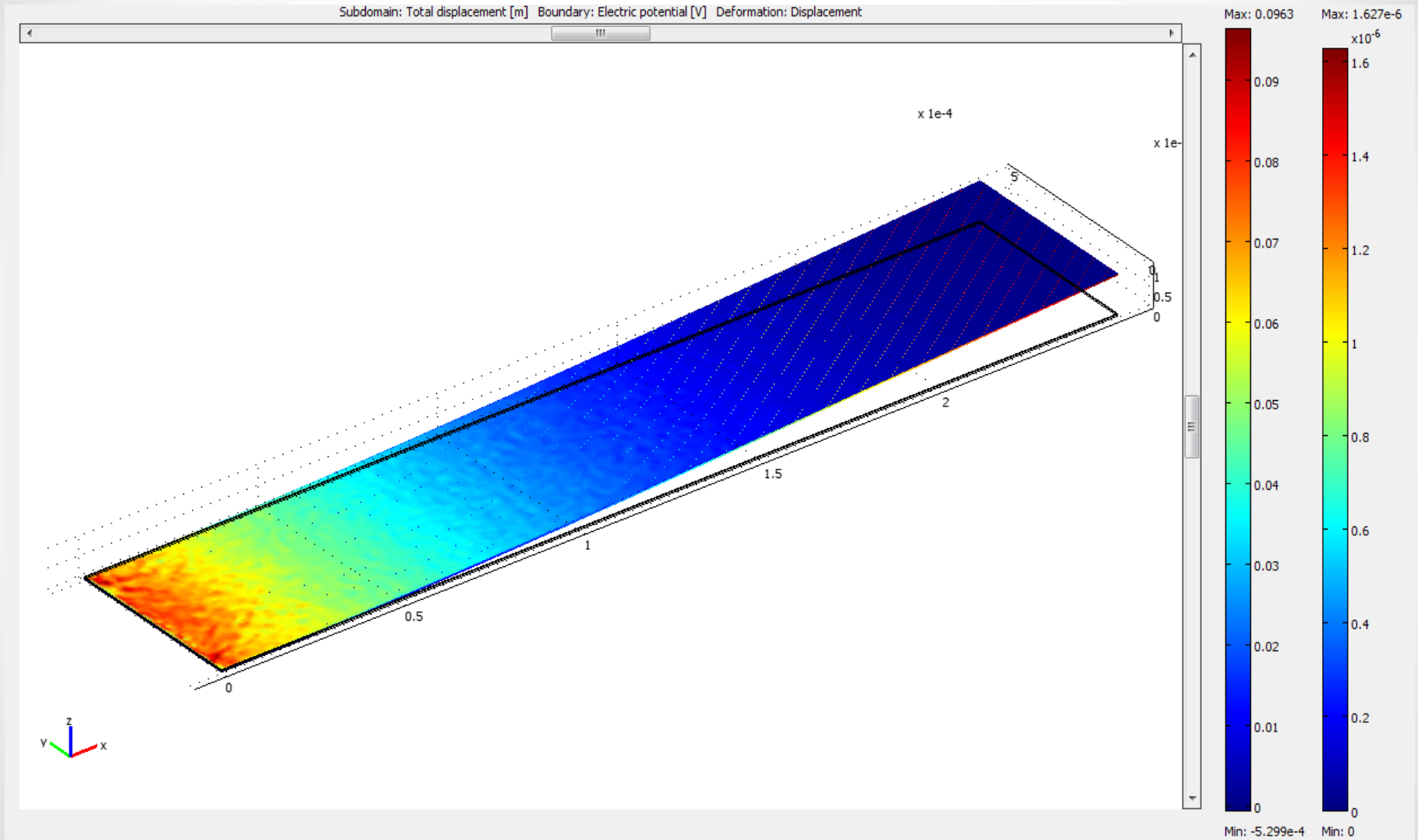
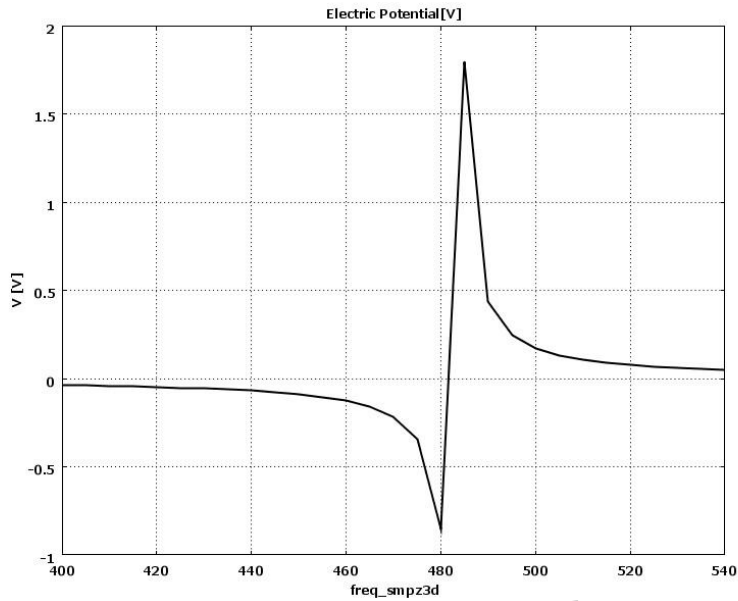
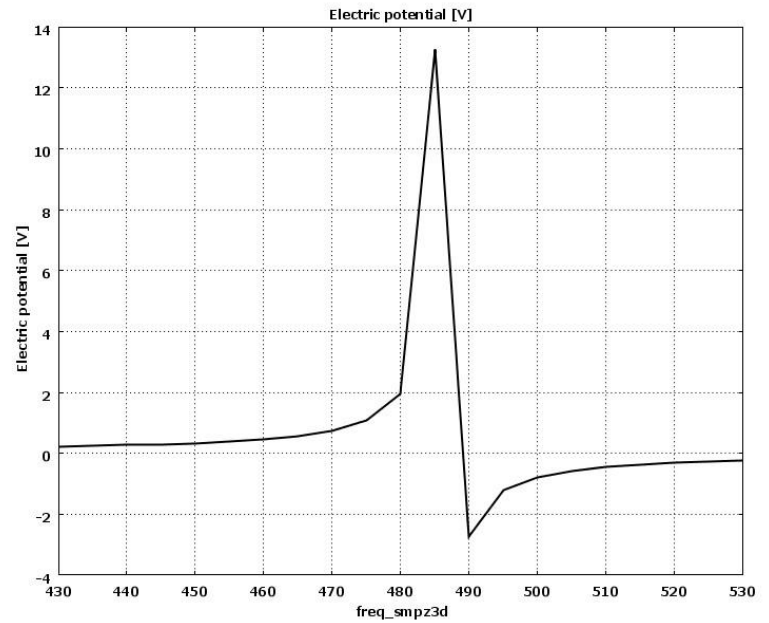


Figure. Tip displacement due to applied Acceleration

# Frequency Analysis

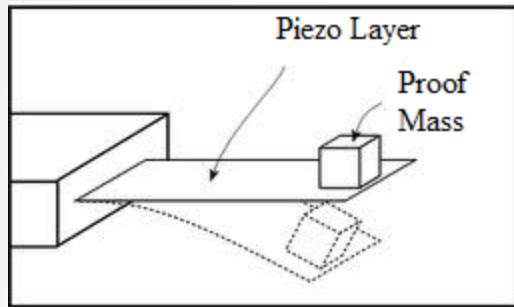


**Figure Frequency Response of *d31***



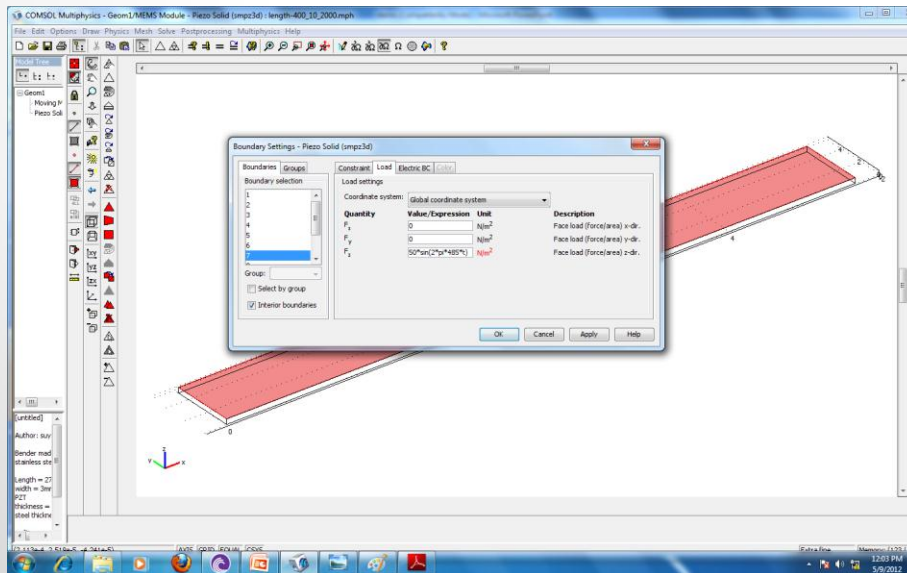
**Figure : Frequency Response of *d33***

# Time dependent Analysis



➤ Harmonic vibration of  $50 \text{ N/m}^2$  amplitude *with* frequency from  $450\text{Hz}$  to  $510\text{Hz}$  is applied on the top surface of beam, so as to produce vibration. The resonant frequency for both  $d_{31}$  and  $d_{33}$  structure is  $585 \text{ Hz}$

➤ Force per unit area is taken as  $50 \text{ N/m}^2$  which is equivalent to a proof mass of  $0.145 \text{ mg}$  deposited on tip of cantilever at  $9.81 \text{ m/s}^2$  acceleration.



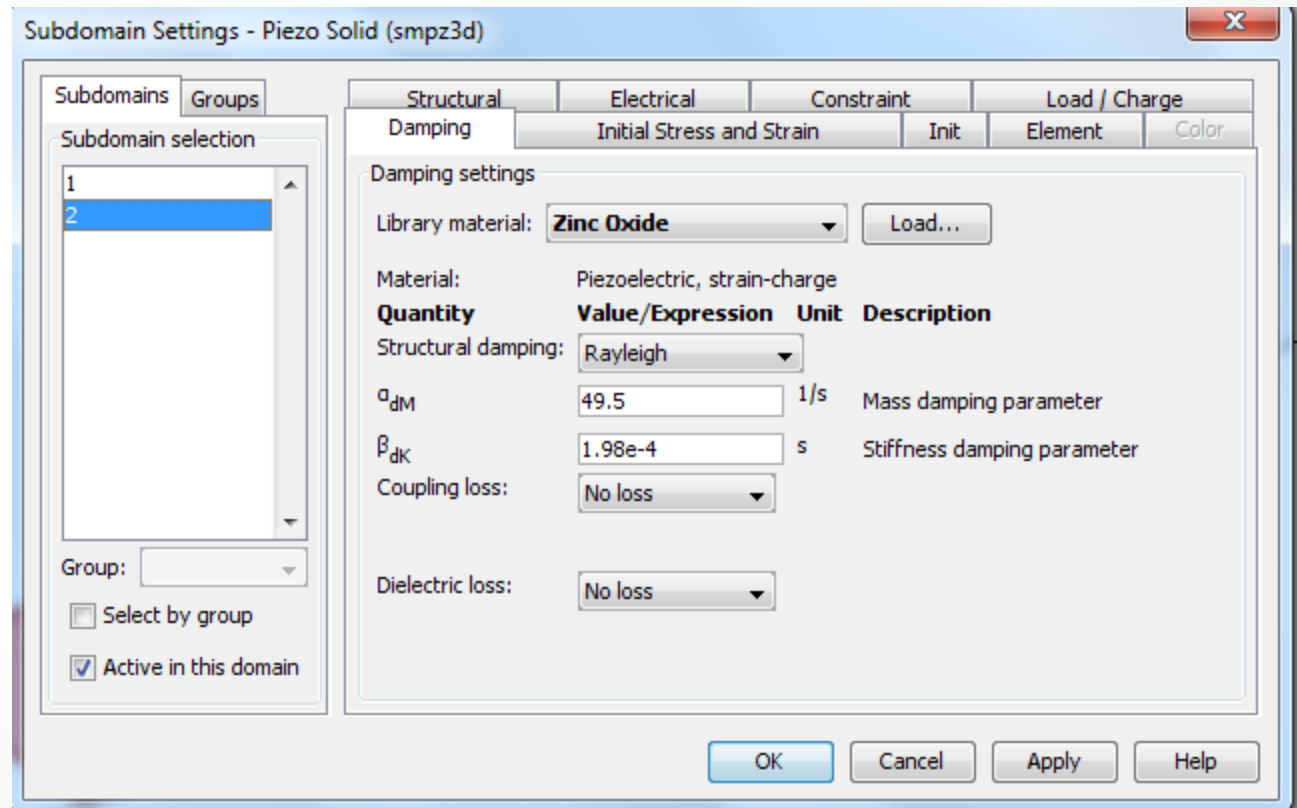
# Damping

Rayleigh damping for transient analysis

$$\begin{bmatrix} \frac{1}{2\omega_1} & \frac{\omega_1}{2} \\ \frac{1}{2\omega_2} & \frac{\omega_2}{2} \end{bmatrix} \begin{bmatrix} \alpha \\ \beta \end{bmatrix} = \begin{bmatrix} \zeta_1 \\ \zeta_2 \end{bmatrix} \quad \zeta_1 = \zeta_2 = 0.1$$

$$\omega_1 = 450$$

$$\omega_2 = 510$$



# Output of Transient Analysis

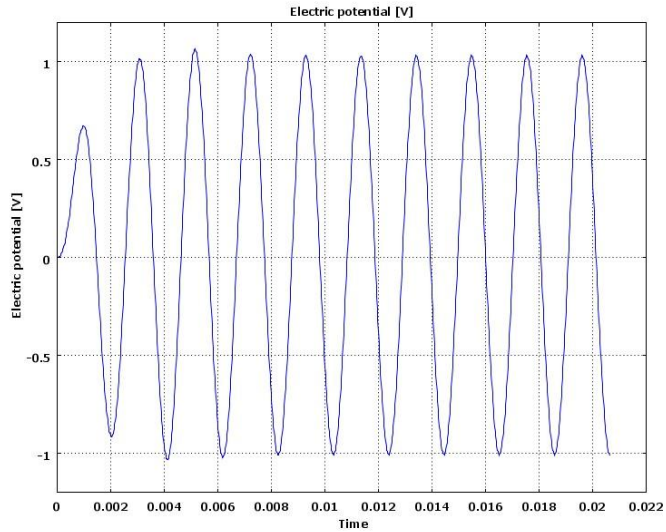


Fig. . Frequency Response of  $a_{31}$  mode

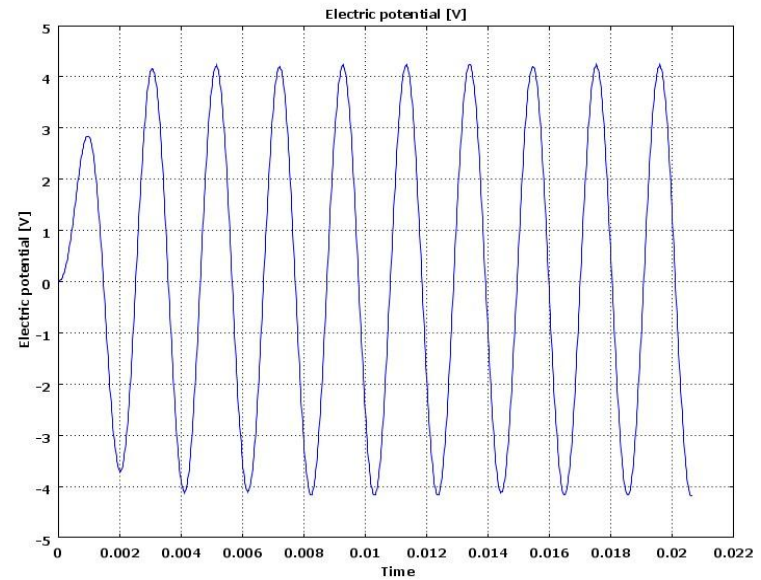
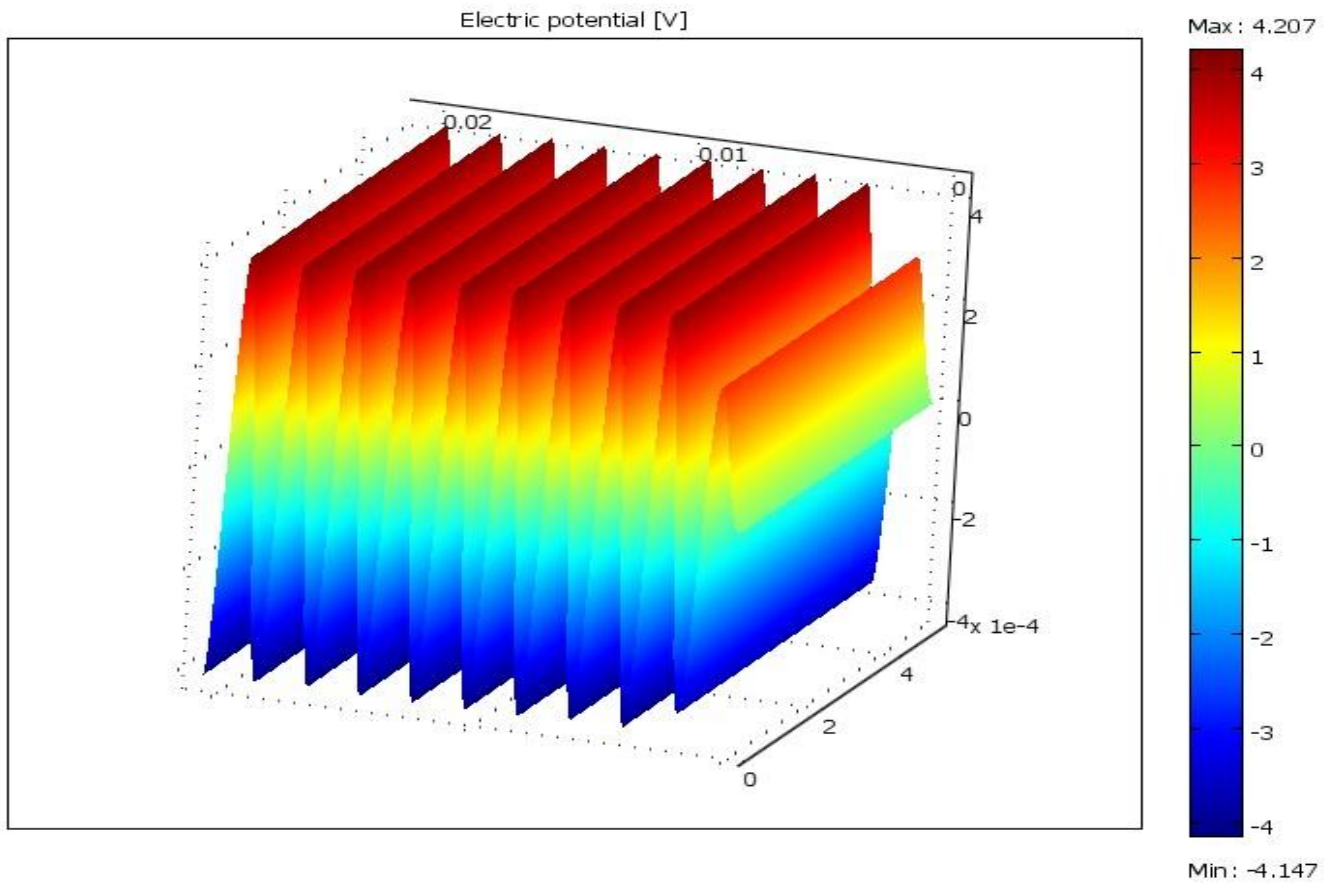


Fig. . Frequency Response of  $a_{33}$  mode



**Figure: Extrusion plot showing total displacement of  $d_{33}$**

# Parametric Segregated Analysis Output

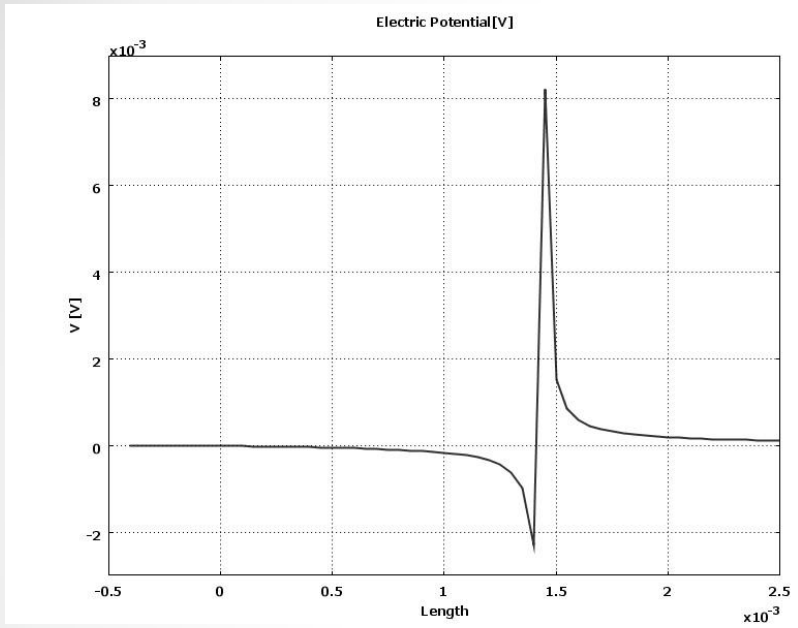


Figure: Plot of total displacement vs length in d31

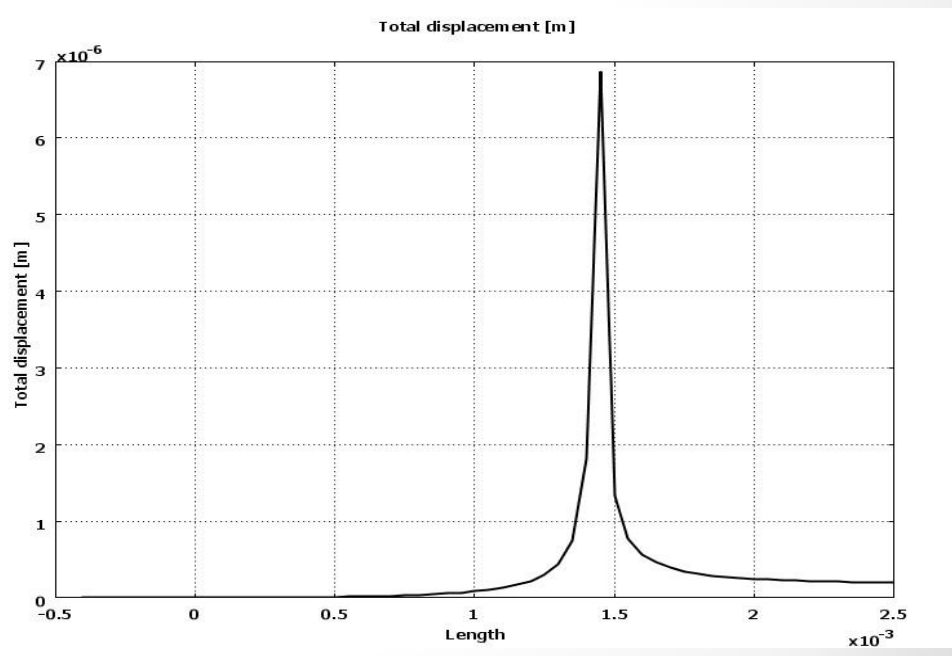
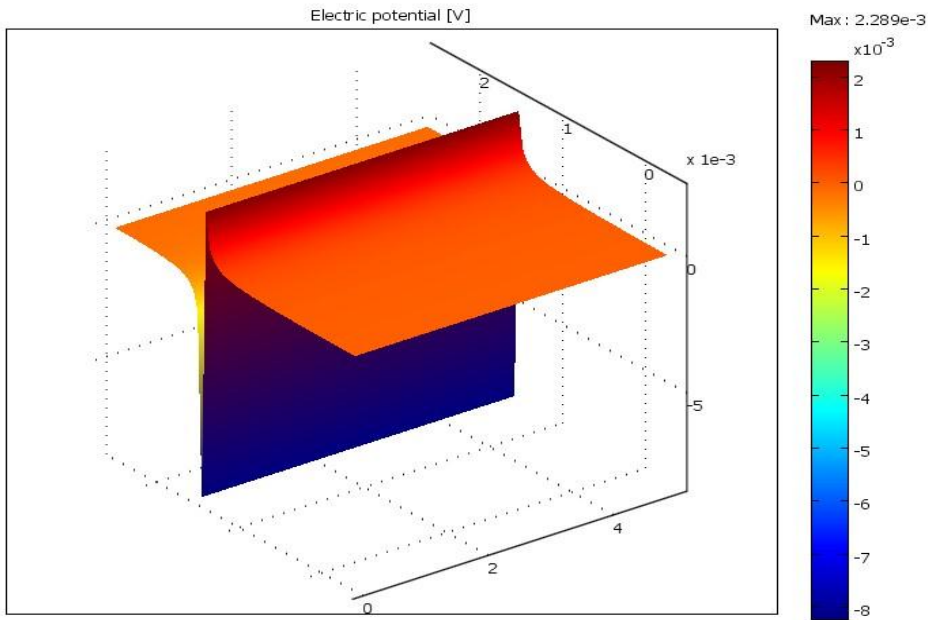
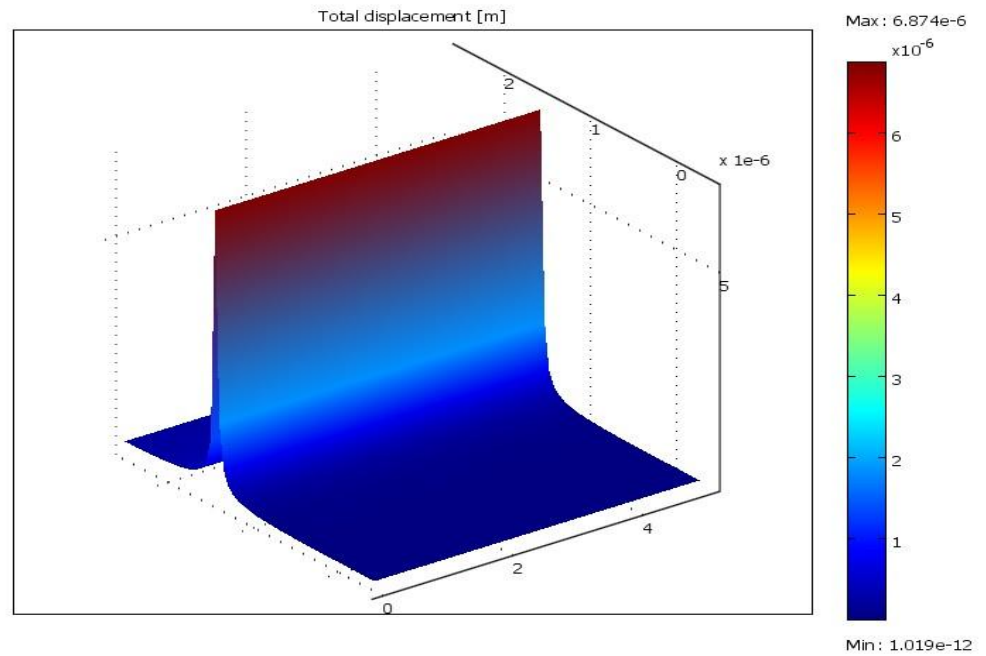


Figure: Plot of total displacement vs length in d33



**Figure : Extrusion plot for maximum voltage.**

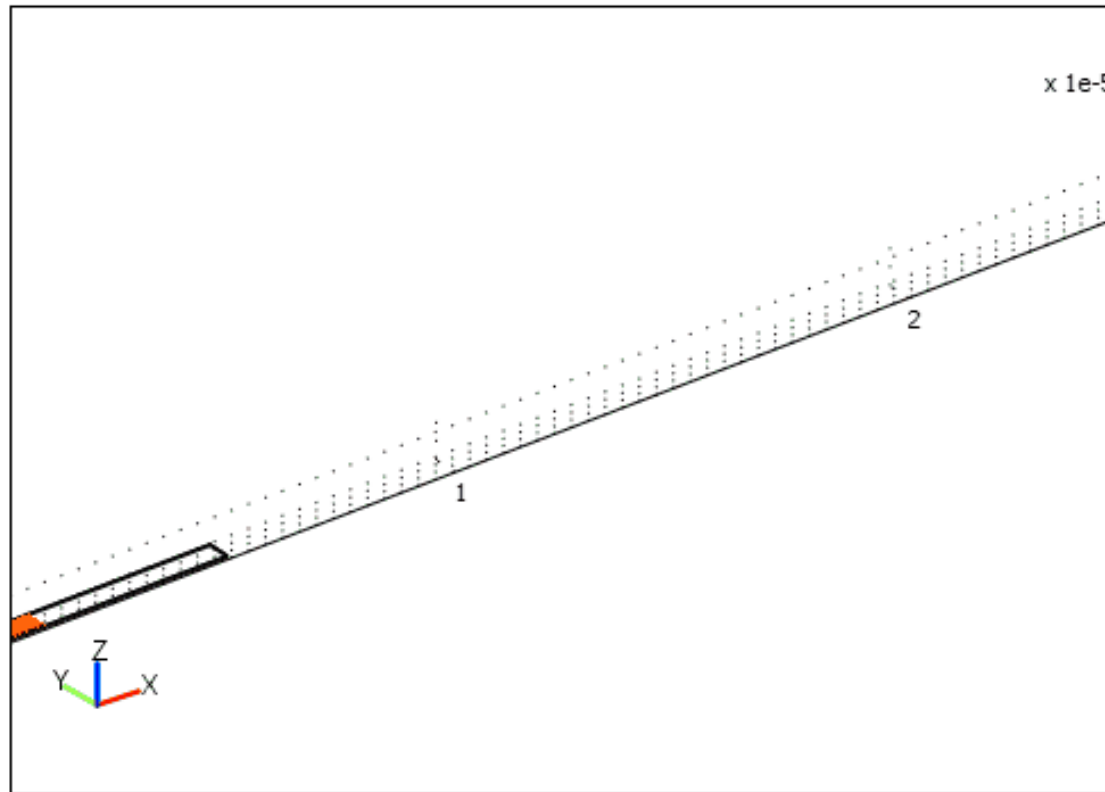


**Figure: Extrusion plot for maximum displacement.**



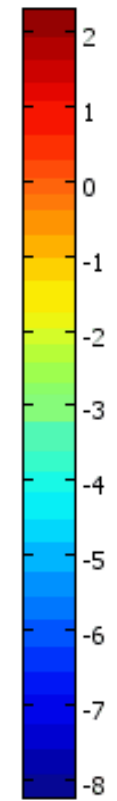
Length(1)=-4e-4

Subdomain: Electric potential [V] Deformation: Displacement amp



Max: 2.289e-3

$\times 10^{-3}$



Min: -8.232e-3

# Figure of Merit

Table . Performance Comparison reported MEMS Harvesters

Ref	Device	Dimension	$V_{peak}$	F(Hz)	Acceleration g	$V/mm^3$	FOM $V/mm^3 \cdot g$
[6]	$d_{31}$ PZT	2mm X 0.6mm X $1.64\mu m$	0.45	608	1	228.7	228.7
[7]	$d_{31}$ PZT	2mmX3.2mmX $1.39\mu m$	16	60	0.79	112.4	142.3
[8]	$d_{31}$ ZnO	27mm x .3mm x 0.2mm.	$4.7 \times 10^{-9}$	10	0.1	$2.9 \times 10^{-4}$	$.9 \times 10^{-9}$
[9]	$d_{33}$ PZT	0.8mmX1mmX $10\mu m$	2.2	528	0.39	275	705
[10]	$d_{33}$ PZT	0.8mmX1.2mmX $2\mu m$	1.6	870	2	833.3	416.6
<b>Proposed</b>	<b><math>d_{31}</math> ZnO</b>	<b>2.5mm x .5mm x <math>2\mu m</math>.</b>	<b>1.05</b>	<b>485</b>	<b>1</b>	<b>420</b>	<b>420</b>
<b>Proposed</b>	<b><math>d_{33}</math> ZnO</b>	<b>2.5mm x .5mm x <math>2\mu m</math></b>	<b>4.2</b>	<b>485</b>	<b>1</b>	<b>1680</b>	<b>1680</b>

# Conclusion

- The work presents the study of piezoelectric cantilevers with engineered extensions to effectively convert ambient vibrations into electricity.
- Piezoelectric converters appear to be the most attractive for Micro-scale devices with a maximum demonstrated power density.
- Vibration powered systems are being actively pursued and will be up and running shortly.

# Acknowledgement

- NPMASS(National program on micro and smart systems) of Govt of India and IISC Bangalore.
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*Thank you.*